

221015US

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
ATSUSHI ITO ET AL : ATTN: APPLICATION DIVISION
SERIAL NO: 10/070,441 :
FILED: March 19, 2002 :
FOR: CERAMIC HEATER FOR A :
SEMICONDUCTOR PRODUCING/ :
EXAMINING DEVICE :

J. Guon
#3/Pre
Amend A
10/2/2002

PRELIMINARY AMENDMENT

ASSISTANT COMMISSIONER FOR PATENTS
WASHINGTON, D.C. 20231

SIR:

Prior to a first examination on the merits, please amend the above-identified application as follows:

IN THE CLAIMS

✓ ✓ ✓ ✓ ✓
Please amend Claim 3 to read as follows:¹

3. (Amended) The ceramic heater for a semiconductor producing/examining device according to claim 1,
wherein a resistance value scattering in said resistance heating element to the average resistance value of said resistance heating element is 5% or less.

¹A marked-up copy of the amendment is attached hereto.